

Features

- AEC-Q101 Qualified
- Split Gate Trench MOSFET Technology
- Excellent Package for Heat Dissipation
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device ^(Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

P-CHANNEL MOSFET

Maximum Ratings

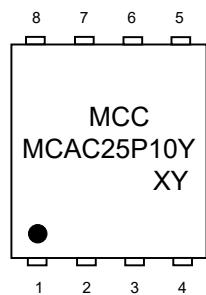
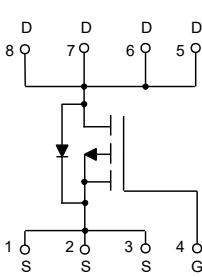
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 50°C/W Junction to Ambient ^(Note 2)
- Thermal Resistance: 1.42°C/W Junction to Case

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	-100	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current T _C =25°C	I _D	-25	A
		-16	
Pulsed Drain Current ^(Note 3)	I _{DM}	-100	A
Total Power Dissipation ^(Note 4)	P _D	88	W
Single Pulsed Avalanche Energy ^(Note 5)	E _{AS}	162	mJ

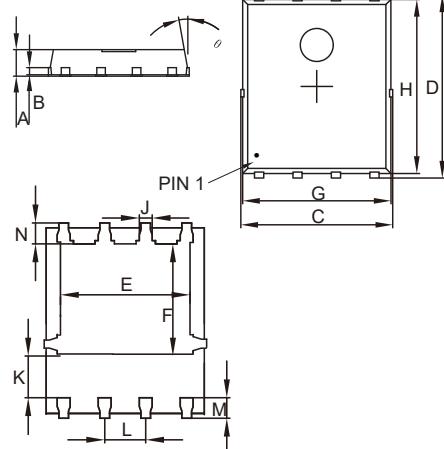
Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds. The value of R_{9JA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-case thermal resistance.
5. T_J=25°C, V_{DD}=-50V, V_{GS}=-10V, L=1mH

Internal Structure and Marking Code



2 codes in total
X is the year
Y is the month



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.031	0.047	0.80	1.20	
B	0.010		0.254		TYP.
C	0.193	0.222	4.90	5.64	
D	0.232	0.250	5.90	6.35	
E	0.148	0.167	3.75	4.25	
F	0.126	0.154	3.20	3.92	
G	0.189	0.213	4.80	5.40	
H	0.222	0.239	5.65	6.06	
K	0.045	0.059	1.15	1.50	
J	0.012	0.020	0.30	0.50	
L	0.046	0.054	1.17	1.37	
M	0.012	0.028	0.30	0.71	
N	0.016	0.028	0.40	0.71	

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250μA	-100			V
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-100V, V _{GS} =0V			-1	μA
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-1	-1.8	-2.5	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-20A		42	55	mΩ
		V _{GS} =-4.5V, I _D =-10A		46	60	
Gate Resistance	R _g	f=1MHz, Open drain		4.9		Ω
Diode Characteristics						
Continuous Body Diode Current	I _S				-25	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-10A			-1.2	V
Reverse Recovery Time	t _{rr}	I _F =-15A,di/dt=100A/μs		50		ns
Reverse Recovery Charge	Q _{rr}			110		nC
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =-50V,V _{GS} =0V,f=1MHz		2077		pF
Output Capacitance	C _{oss}			222		
Reverse Transfer Capacitance	C _{rss}			16		
Total Gate Charge	Q _g	V _{DS} =-50V,V _{GS} =-10V,I _D =-15A		36		nC
Gate-Source Charge	Q _{gs}			5.6		
Gate-Drain Charge	Q _{gd}			6.6		
Turn-On Delay Time	t _{d(on)}	V _{DD} =-50V, V _{GS} =-10V, R _G =6Ω, I _{DS} =-15A		10		ns
Turn-On Rise Time	t _r			12.5		
Turn-Off Delay Time	t _{d(off)}			77.6		
Turn-Off Fall Time	t _f			27.6		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

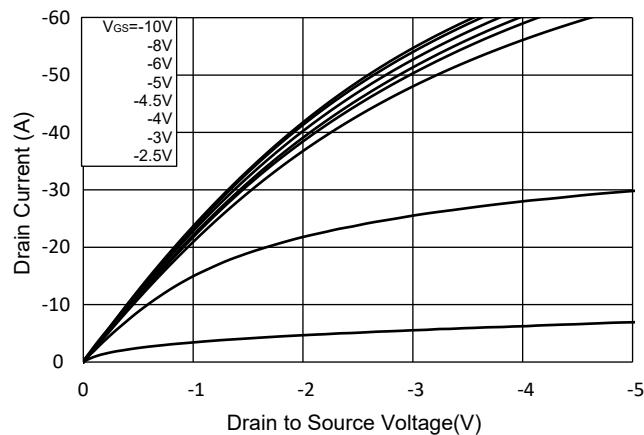


Fig.2 Transfer Characteristic

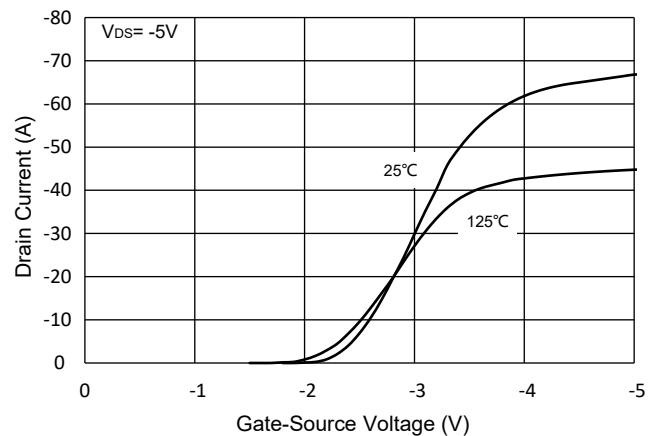


Fig.3 Rdson-Vgs

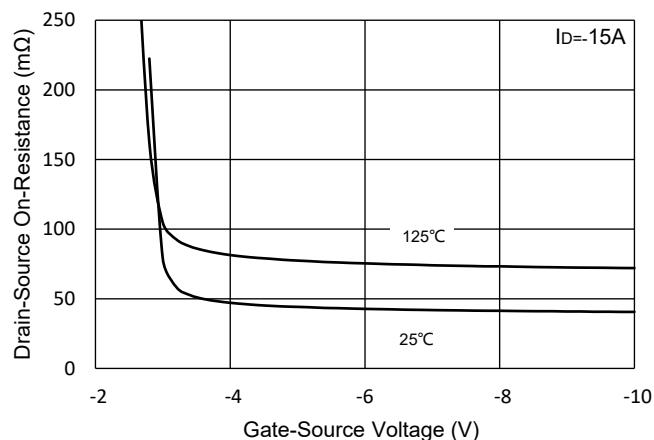


Fig.4 R_{DSON}-I_D

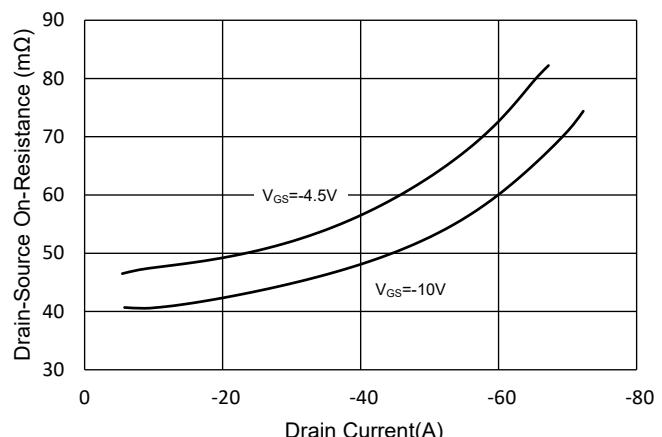


Fig.5 Capacitance Characteristics

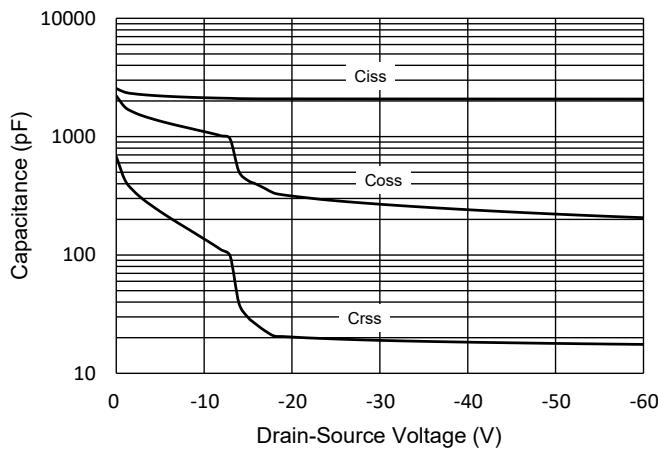
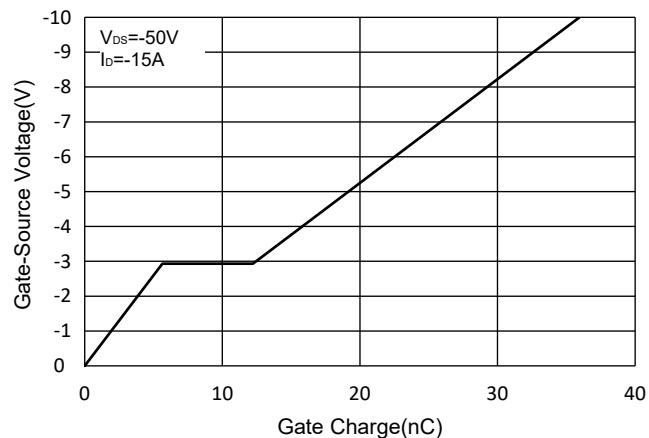
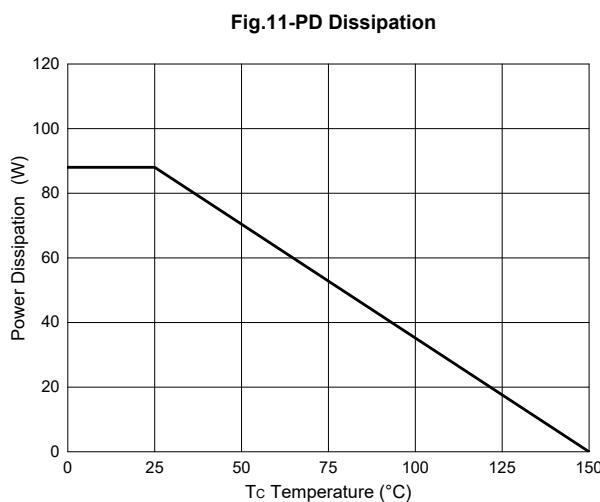
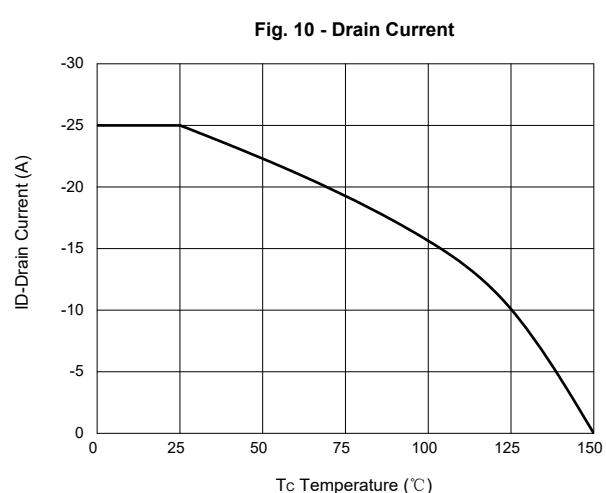
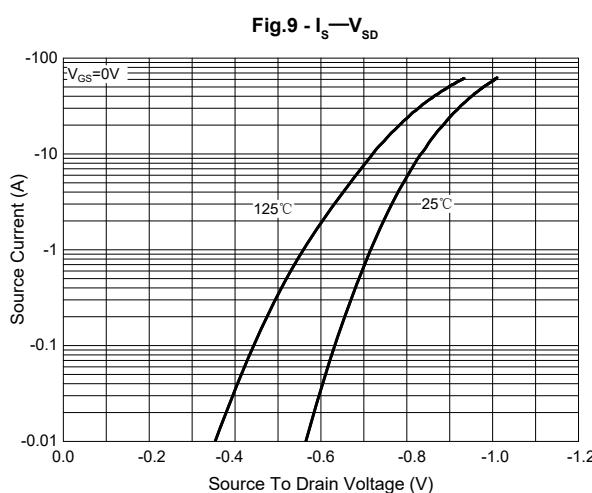
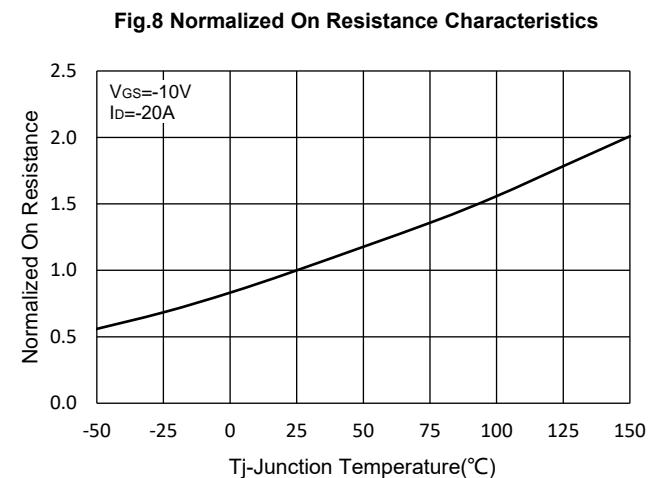
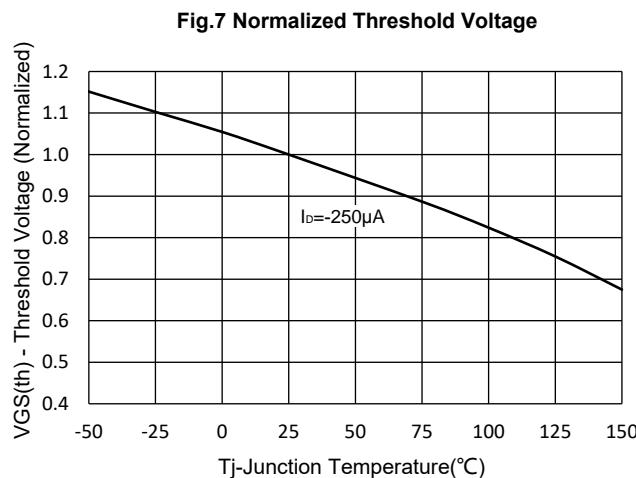


Fig.6 Gate Charge



Curve Characteristics



Curve Characteristics

Fig. 12 - Safe Operation Area

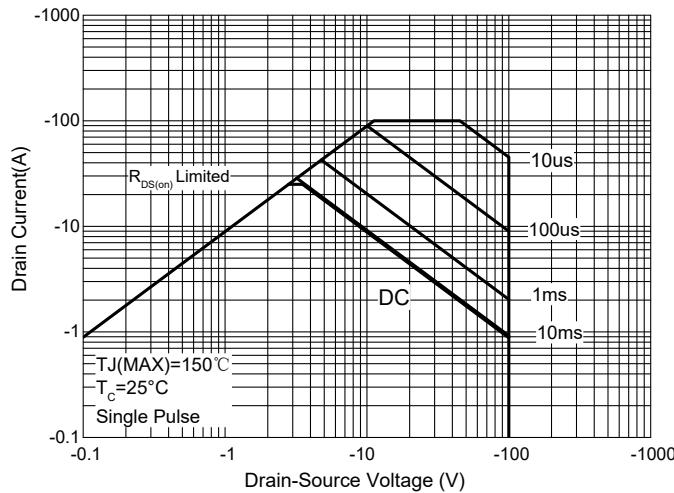
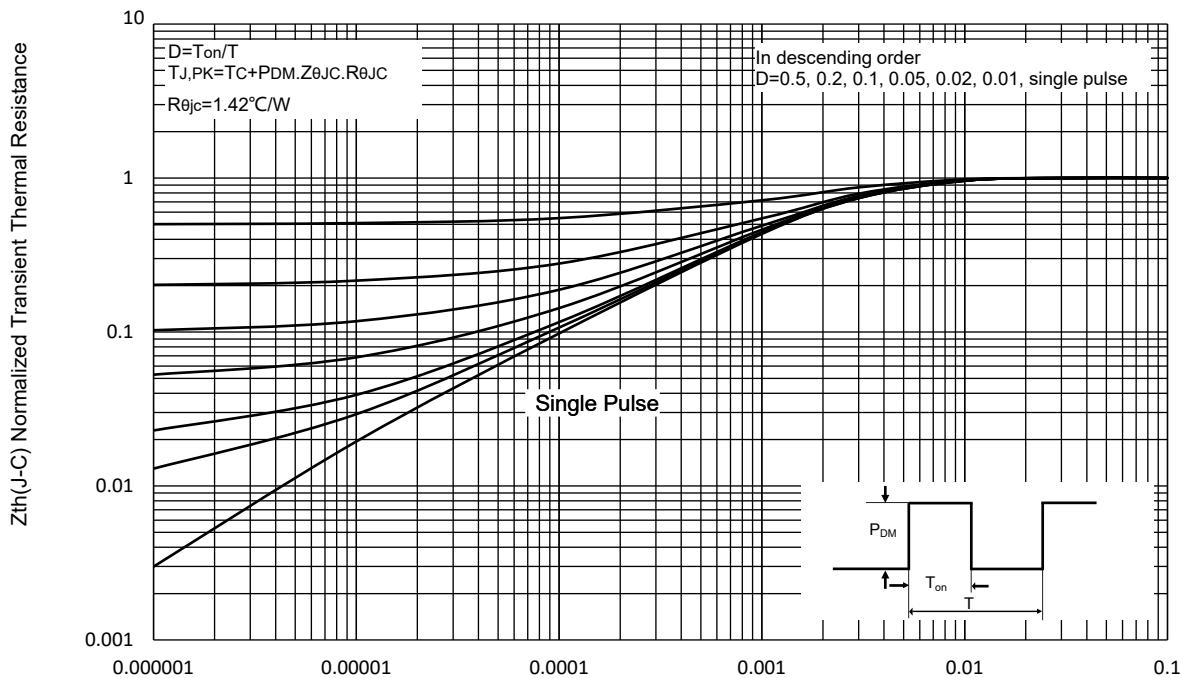


Fig.13 Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 5Kpcs/Reel

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